

UNR411x Series (UN411x Series)

Silicon PNP epitaxial planar type

For digital circuits

■ Features

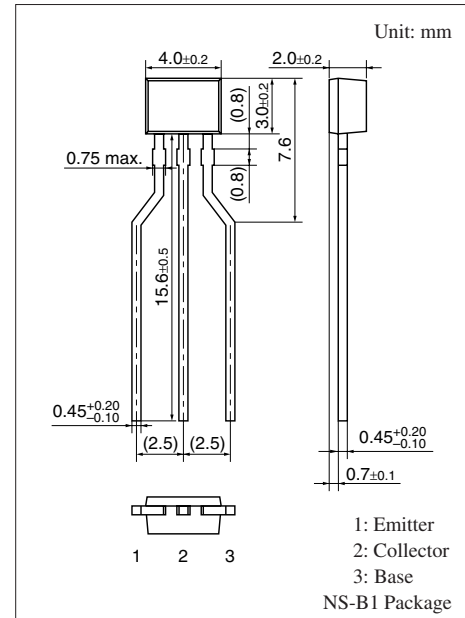
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts
- New S type package, allowing supply with the radial taping

■ Resistance by Part Number

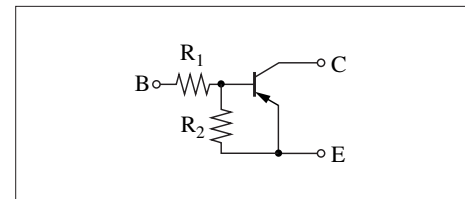
	(R ₁)	(R ₂)
• UNR4110 (UN4110)	47 kΩ	—
• UNR4111 (UN4111)	10 kΩ	10 kΩ
• UNR4112 (UN4112)	22 kΩ	22 kΩ
• UNR4113 (UN4113)	47 kΩ	47 kΩ
• UNR4114 (UN4114)	10 kΩ	47 kΩ
• UNR4115 (UN4115)	10 kΩ	—
• UNR4116 (UN4116)	4.7 kΩ	—
• UNR4117 (UN4117)	22 kΩ	—
• UNR4118 (UN4118)	0.51 kΩ	5.1 kΩ
• UNR4119 (UN4119)	1 kΩ	10 kΩ
• UNR411D (UN411D)	47 kΩ	10 kΩ
• UNR411E (UN411E)	47 kΩ	22 kΩ
• UNR411F (UN411F)	4.7 kΩ	10 kΩ
• UNR411H (UN411H)	2.2 kΩ	10 kΩ
• UNR411L (UN411L)	4.7 kΩ	4.7 kΩ
• UNR411M	2.2 kΩ	47 kΩ
• UNR411N	4.7 kΩ	47 kΩ

■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-50	V
Collector-emitter voltage (Base open)	V _{CEO}	-50	V
Collector current	I _C	-100	mA
Total power dissipation	P _T	300	mW
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



Internal Connection



Note) The part numbers in the parenthesis show conventional part number.

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter		Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)		V_{CBO}	$I_C = -10 \mu\text{A}, I_E = 0$	-50			V
Collector-emitter voltage (Base open)		V_{CEO}	$I_C = -2 \text{mA}, I_B = 0$	-50			V
Collector-base cutoff current (Emitter open)		I_{CBO}	$V_{CB} = -50 \text{V}, I_E = 0$			-0.1	μA
Collector-emitter cutoff current (Base open)		I_{CEO}	$V_{CE} = -50 \text{V}, I_B = 0$			-0.5	μA
Emitter-base cutoff current (Collector open)	UNR4110/4115/4116/4117	I_{EBO}	$V_{EB} = -6 \text{V}, I_C = 0$			-0.01	mA
	UNR4113					-0.1	
	UNR4112/4114/411D/ 411E/411M/411N					-0.2	
	UNR4111					-0.5	
	UNR411F/411H					-1.0	
	UNR4119					-1.5	
	UNR4118/411L					-2.0	
Forward current transfer ratio	UNR4118/411L	h_{FE}	$V_{CE} = -10 \text{V}, I_C = -5 \text{mA}$	20			—
	UNR4119/411D/411F/411H			30			
	UNR4111			35			
	UNR4112/411E			60			
	UNR4113/4114/411M			80			
	UNR411N			80	400		
	UNR4110*/4115*/4116*/ 4117*			160	460		
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = -10 \text{mA}, I_B = -0.3 \text{mA}$			-0.25	V
Output voltage high-level		V_{OH}	$V_{CC} = -5 \text{V}, V_B = -0.5 \text{V}, R_L = 1 \text{k}\Omega$	-4.9			V
Output voltage low-level		V_{OL}	$V_{CC} = -5 \text{V}, V_B = -2.5 \text{V}, R_L = 1 \text{k}\Omega$			-0.2	V
			$V_{CC} = -5 \text{V}, V_B = -3.5 \text{V}, R_L = 1 \text{k}\Omega$				
			$V_{CC} = -5 \text{V}, V_B = -10 \text{V}, R_L = 1 \text{k}\Omega$				
			$V_{CC} = -5 \text{V}, V_B = -6 \text{V}, R_L = 1 \text{k}\Omega$				
Transition frequency		f_T	$V_{CB} = -10 \text{V}, I_E = 1 \text{mA}, f = 200 \text{MHz}$		80		MHz
Input resistance	UNR4118	R_i		-30%	0.51	+30%	k Ω
	UNR4119				1.0		
	UNR411H/411M				2.2		
	UNR4116/411F/411L/411N				4.7		
	UNR4111/4114/4115				10		
	UNR4112/4117				22		
	UNR4110/4113/411D/411E				47		

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

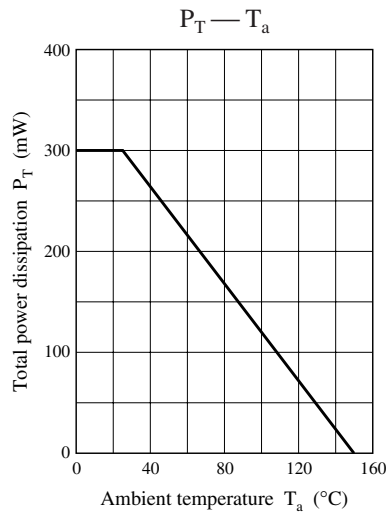
Rank	Q	R	S	No-rank
h_{FE}	160 to 260	210 to 340	290 to 460	160 to 460

■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

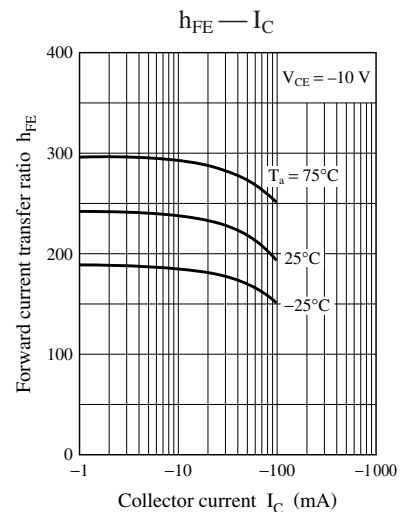
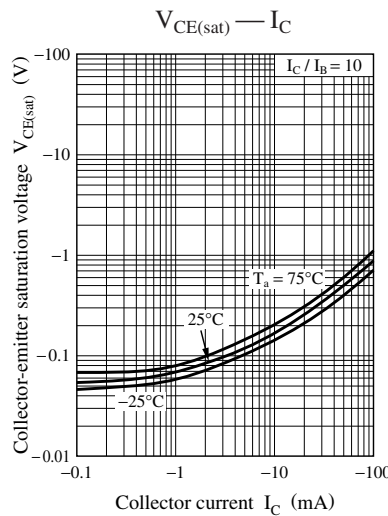
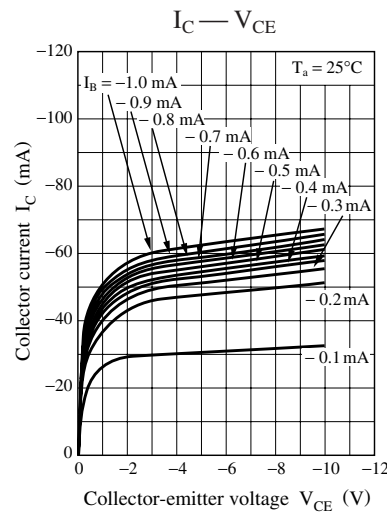
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Resistance ratio	UNR411M	R_1/R_2		0.047		—
	UNR411N			0.1		
	UNR4118/4119			0.08	0.10	0.12
	UNR4114			0.17	0.21	0.25
	UNR411H			0.17	0.22	0.27
	UNR411F			0.37	0.47	0.57
	UNR4111/4112/4113/411L			0.8	1.0	1.2
	UNR411E			1.70	2.14	2.60
	UNR411D			3.7	4.7	5.7

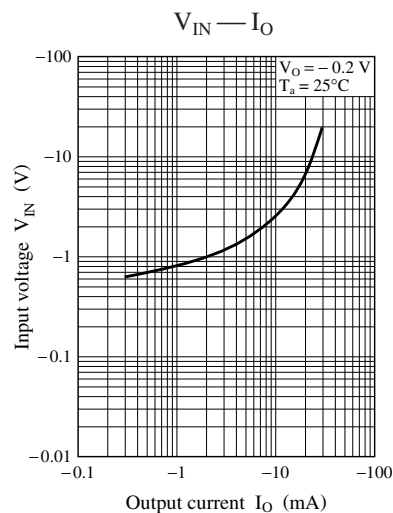
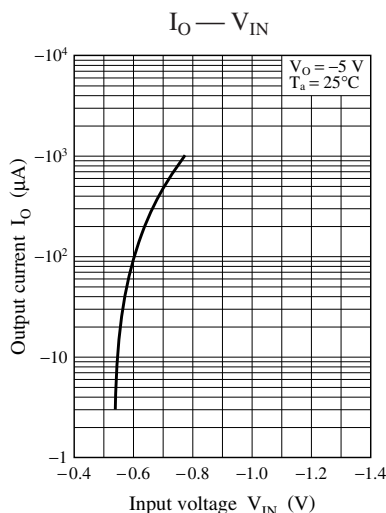
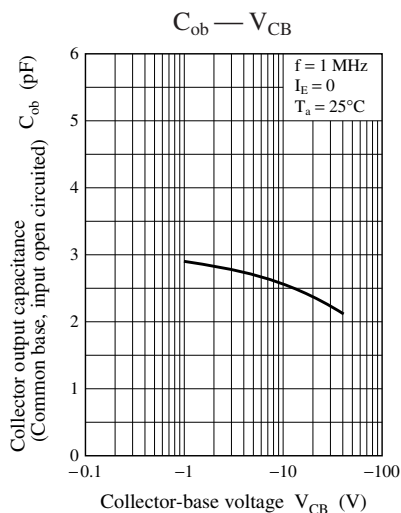
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Common characteristics chart

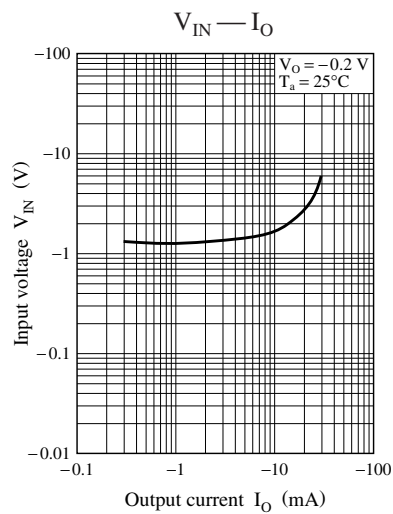
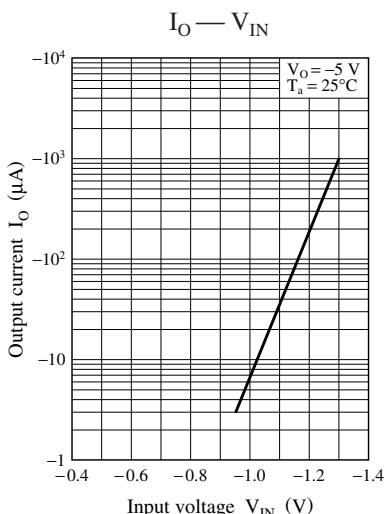
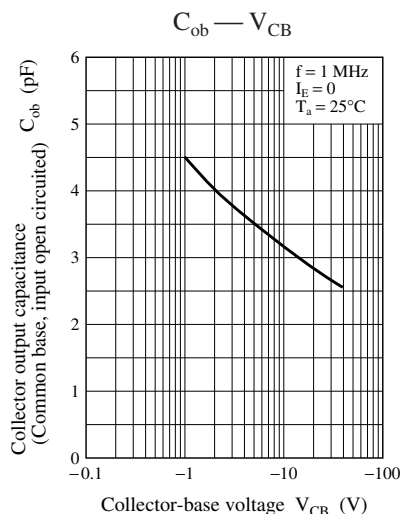
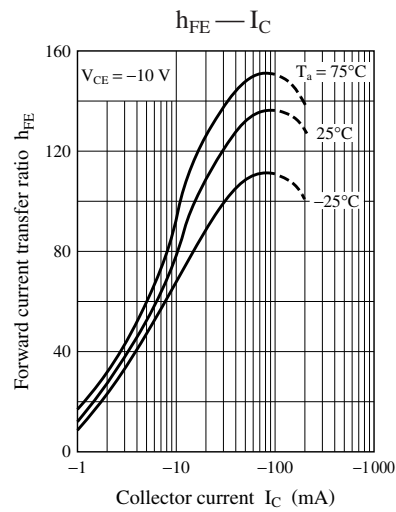
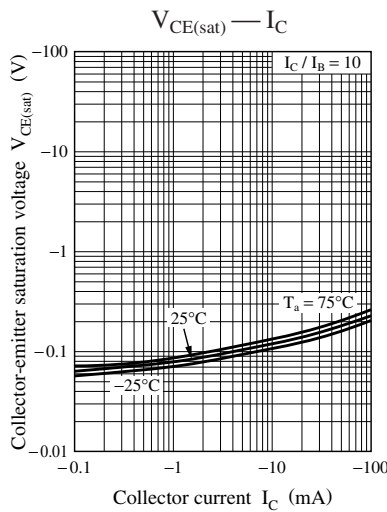
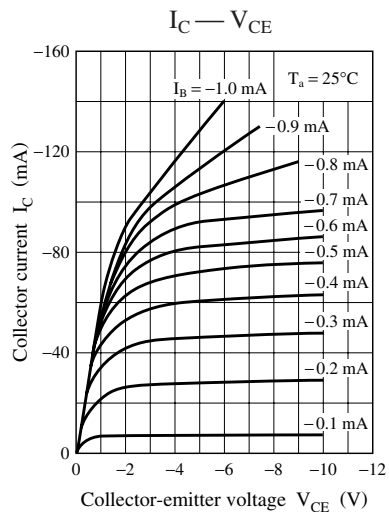


Characteristics charts of UNR4110

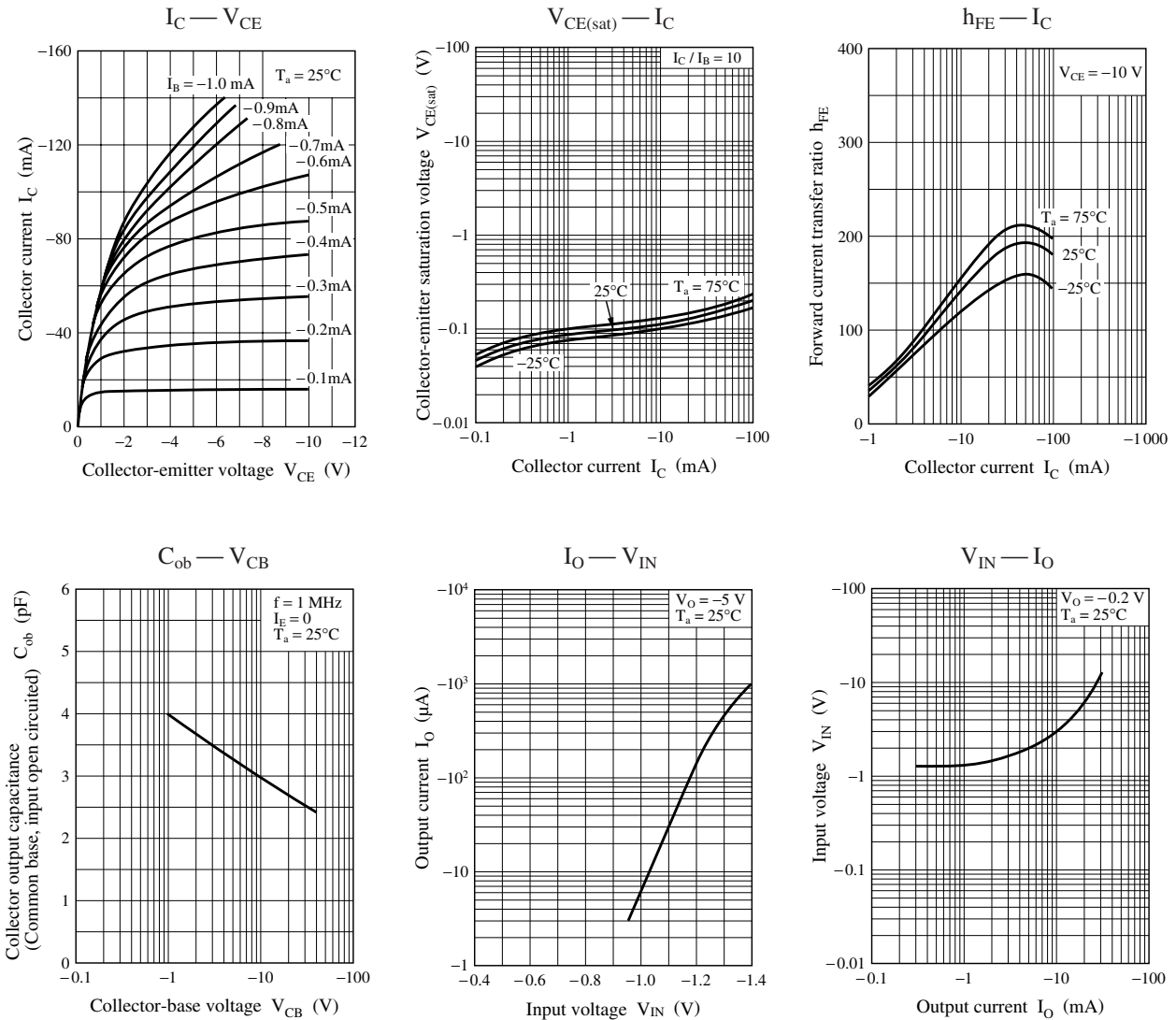




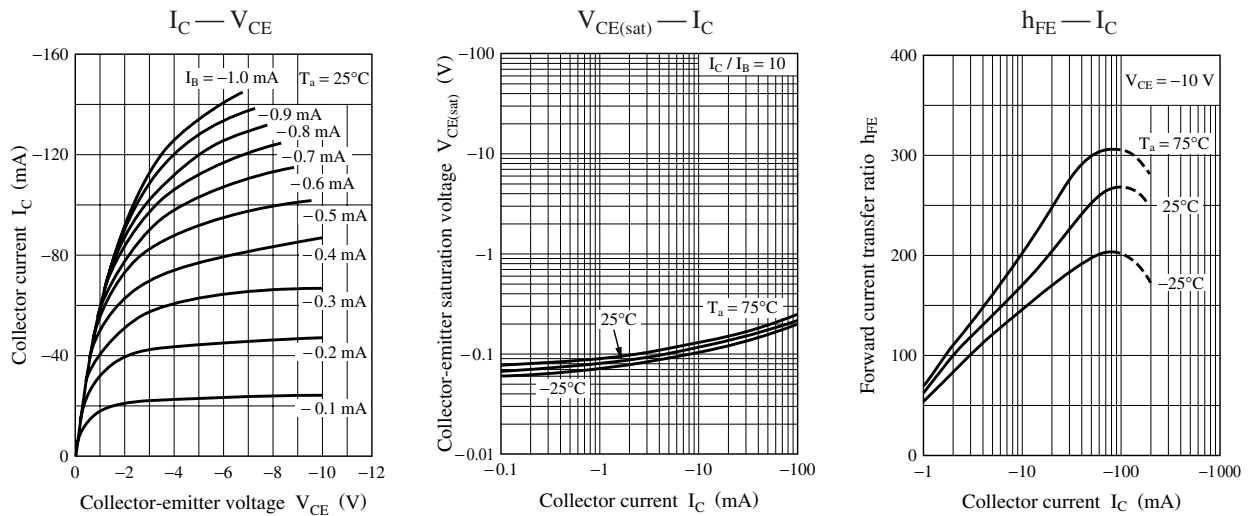
Characteristics charts of UNR4111

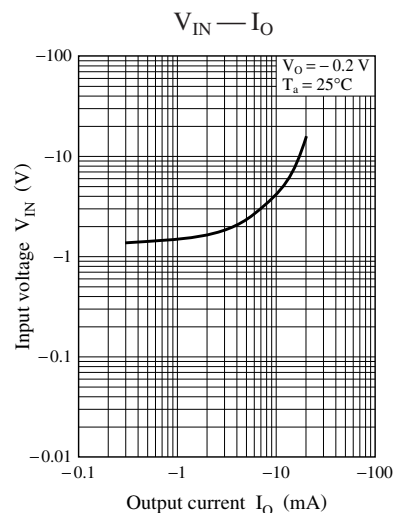
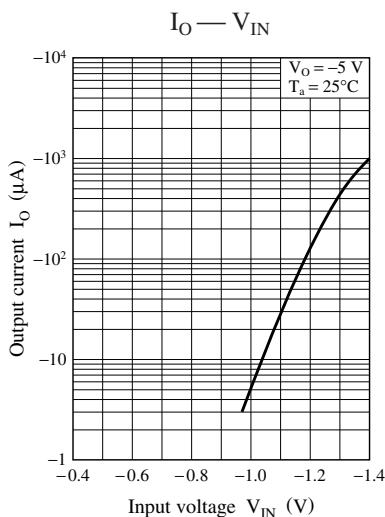
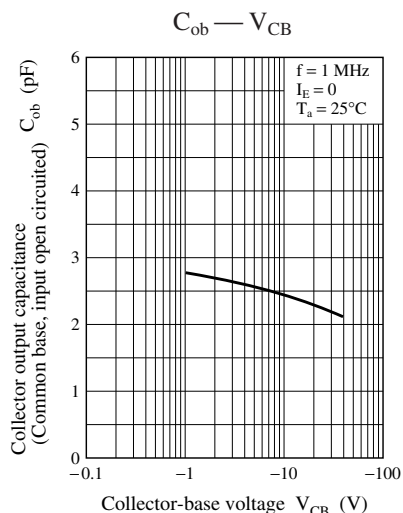


Characteristics charts of UNR4112

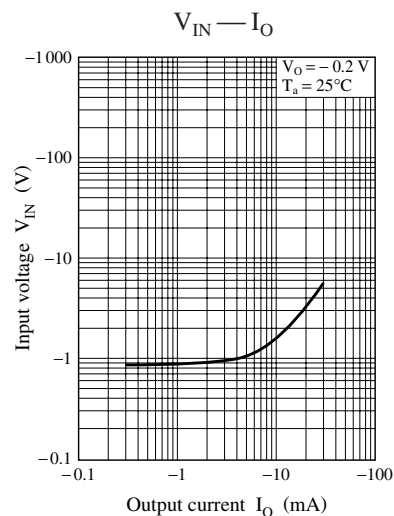
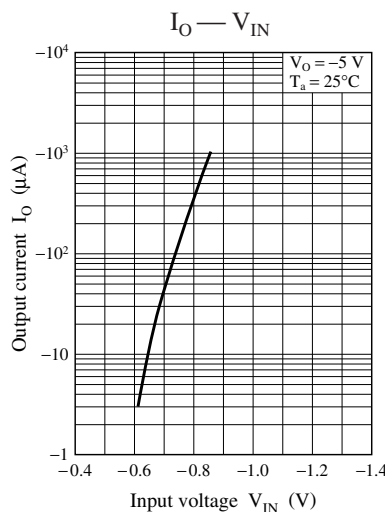
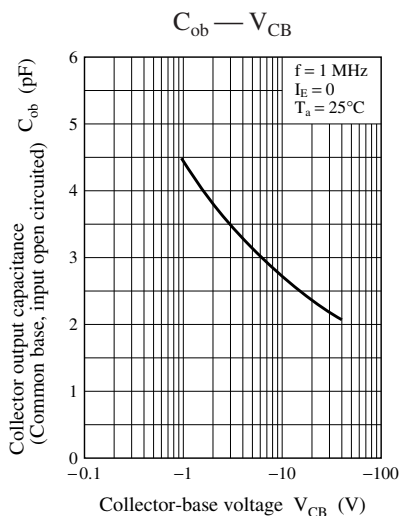
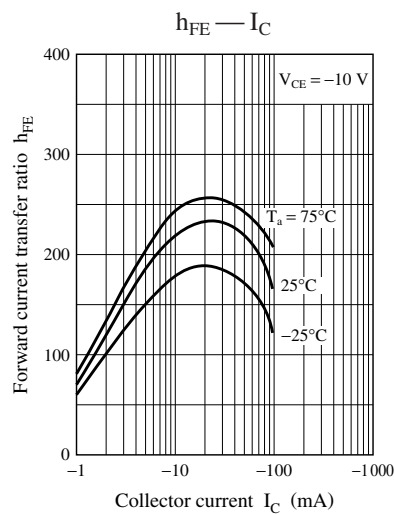
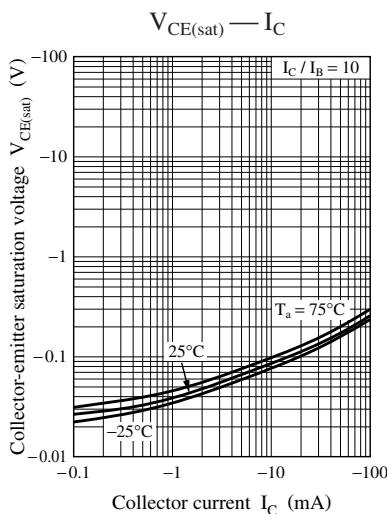
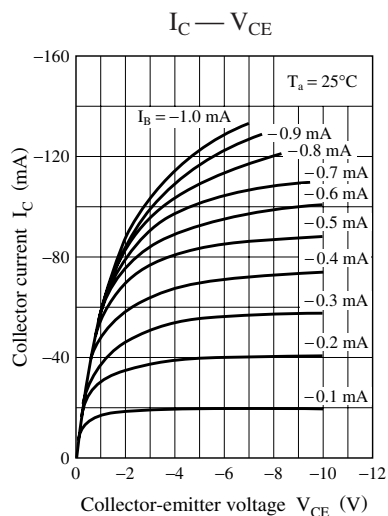


Characteristics charts of UNR4113

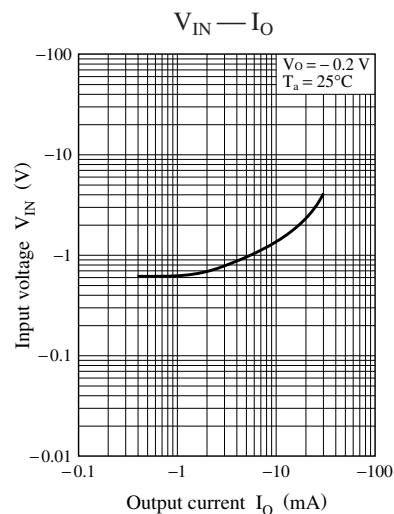
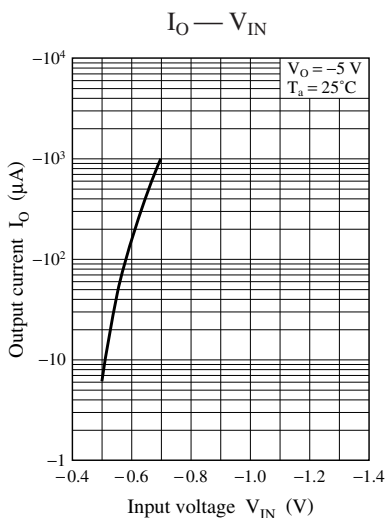
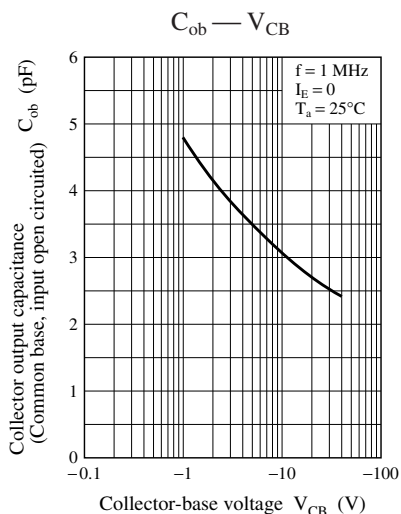
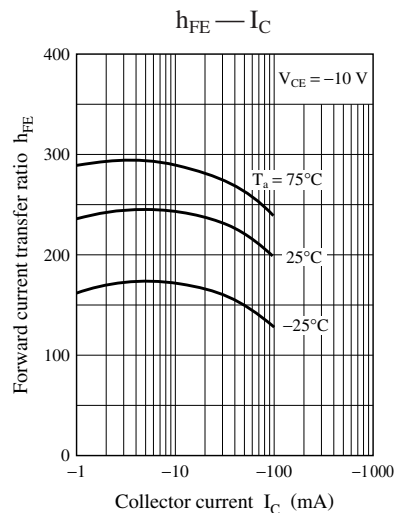
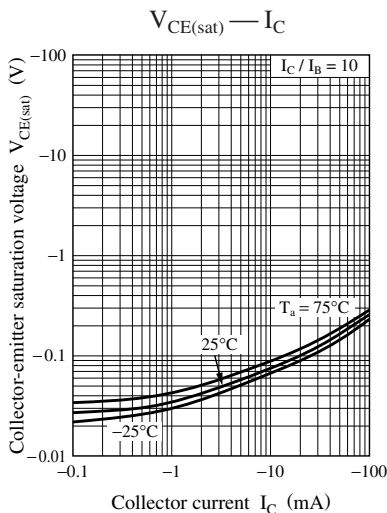
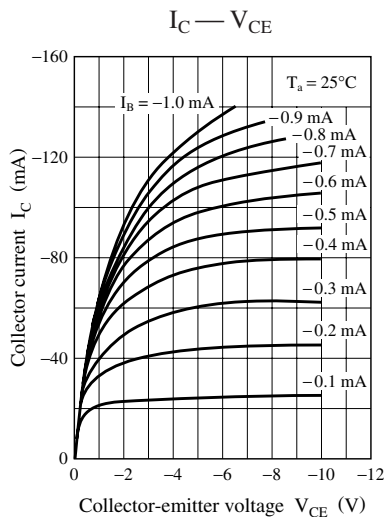




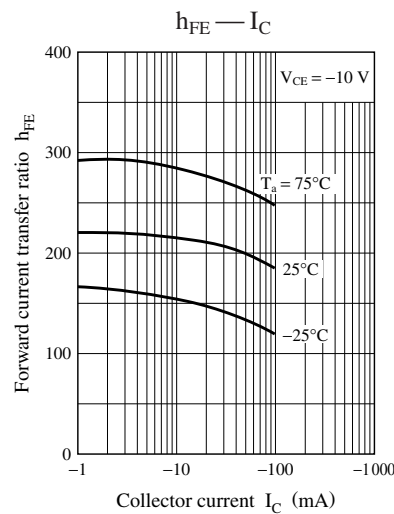
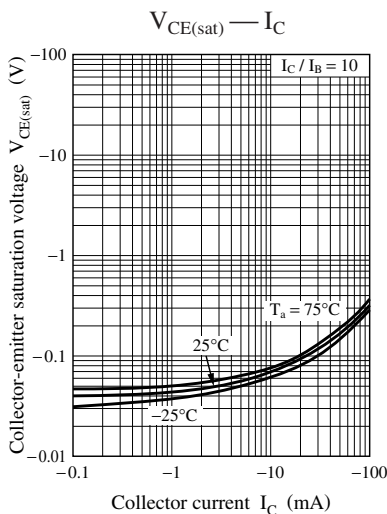
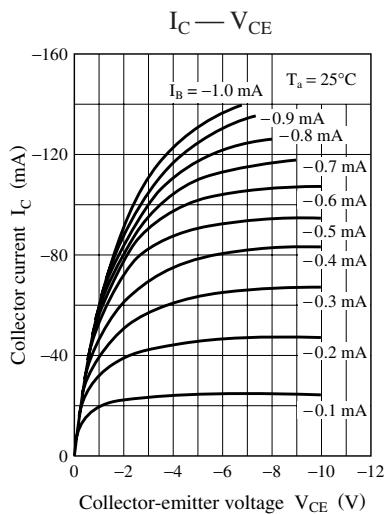
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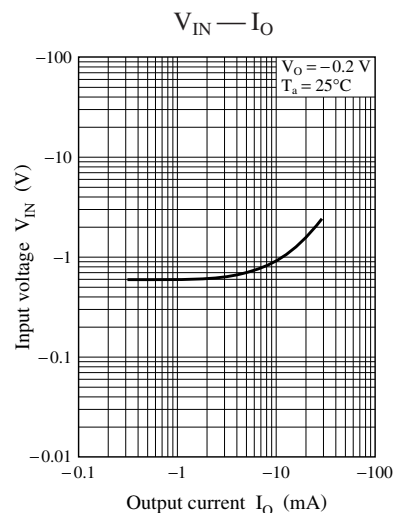
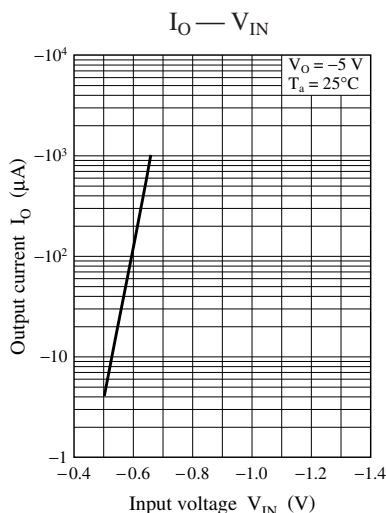
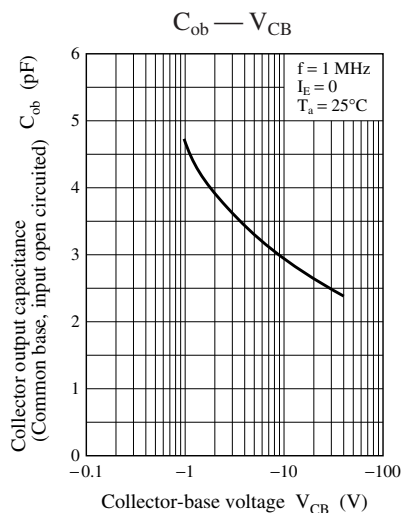


Characteristics charts of UNR4115

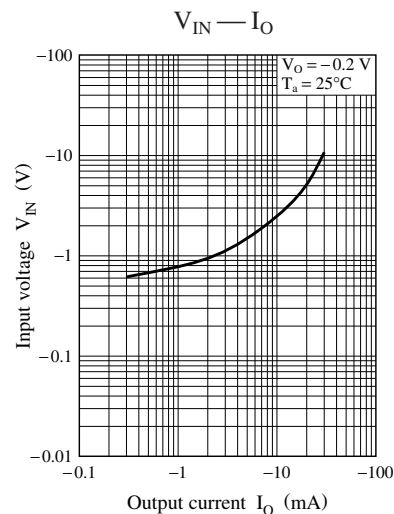
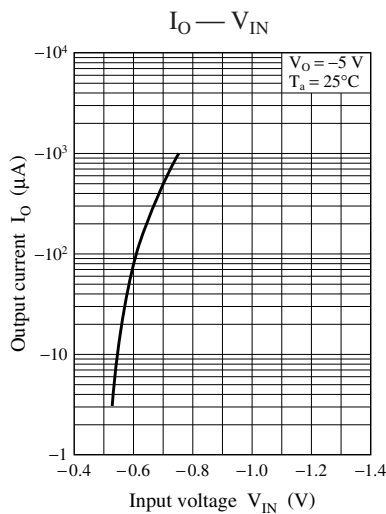
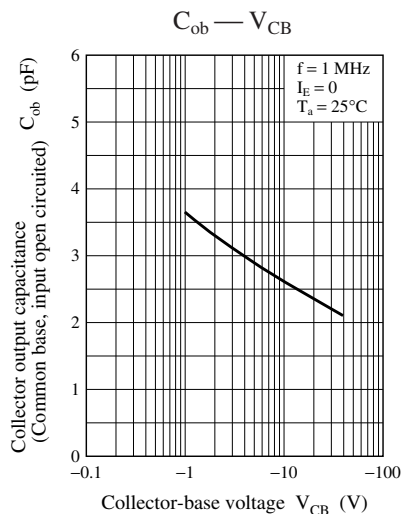
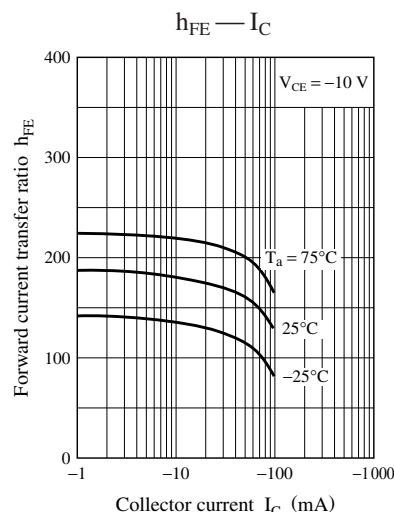
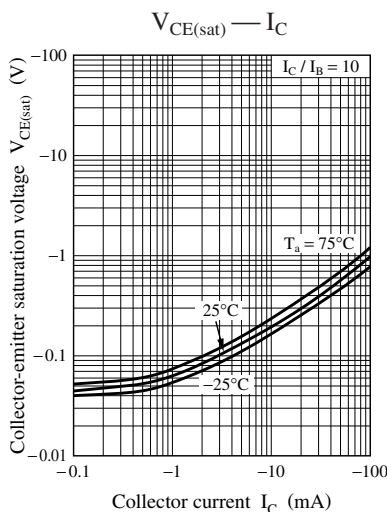
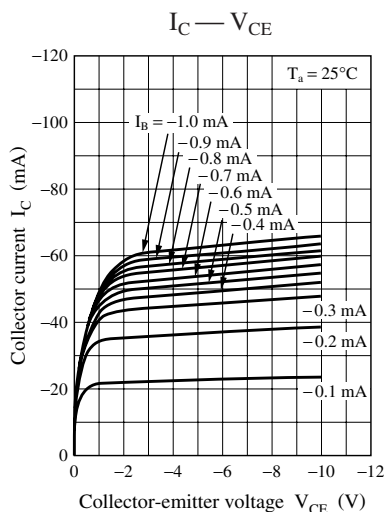


Characteristics charts of UNR4116

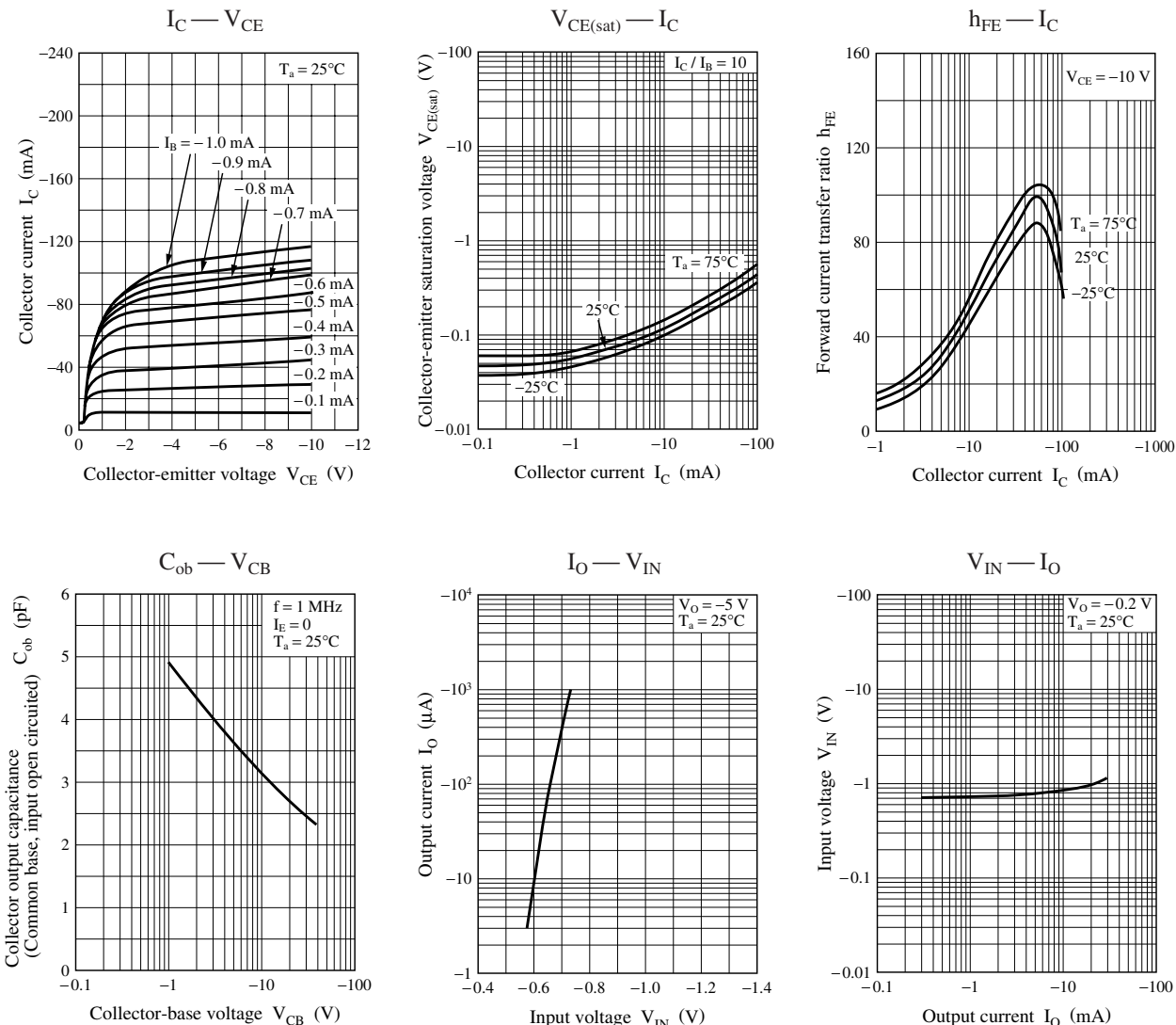




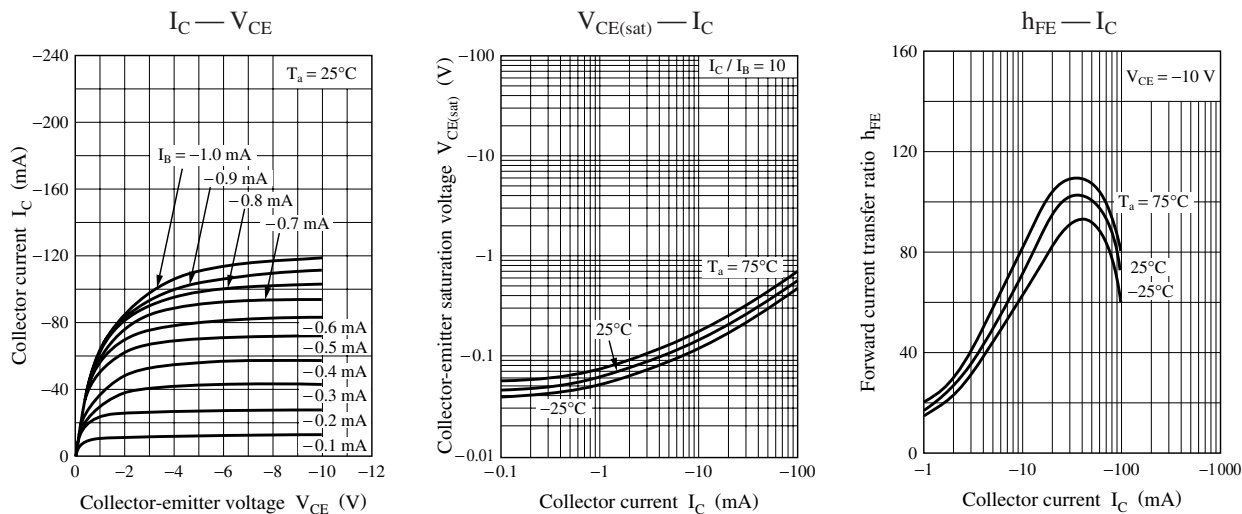
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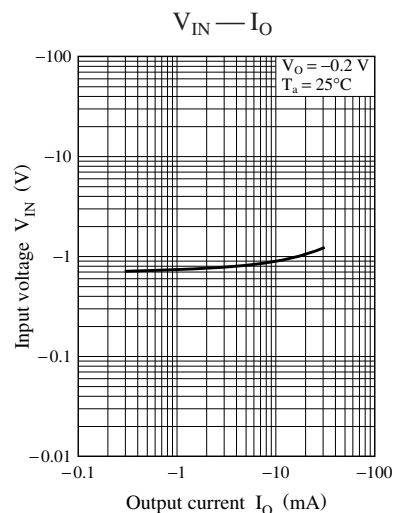
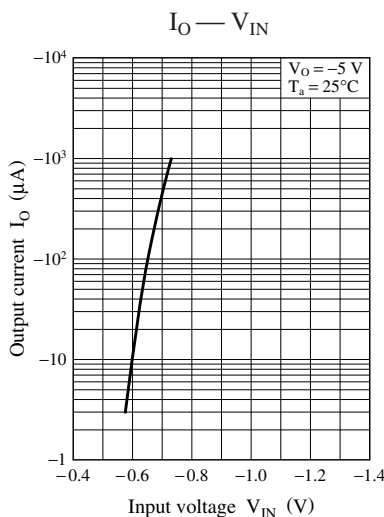
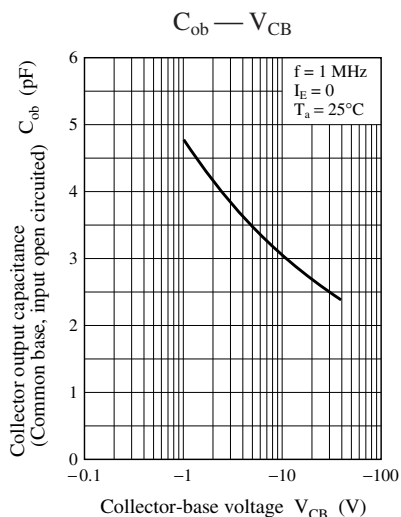


Characteristics charts of UNR4118

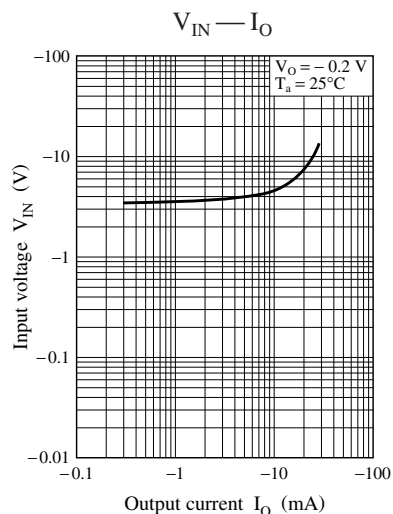
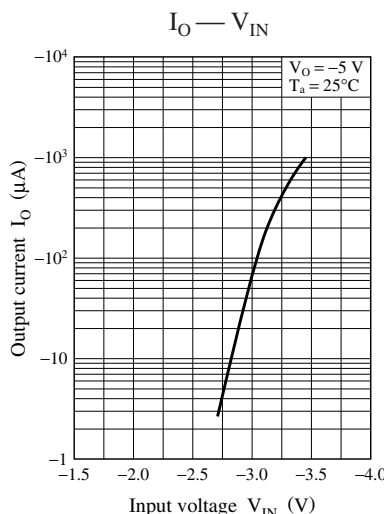
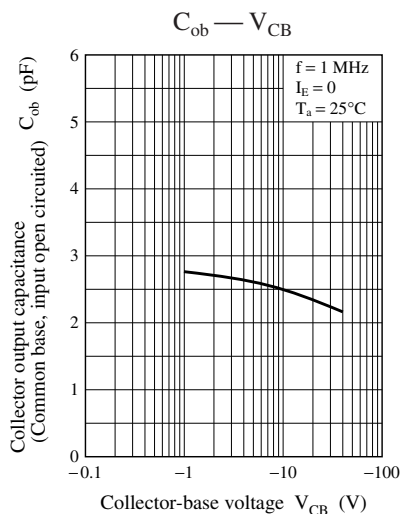
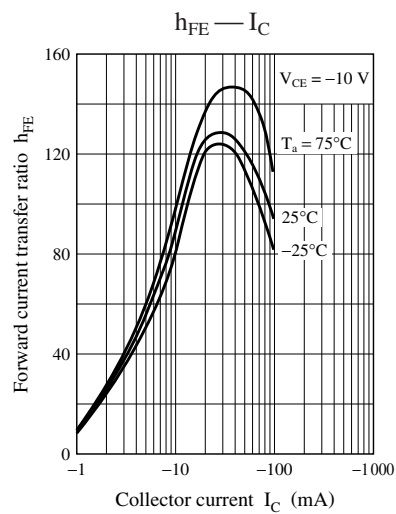
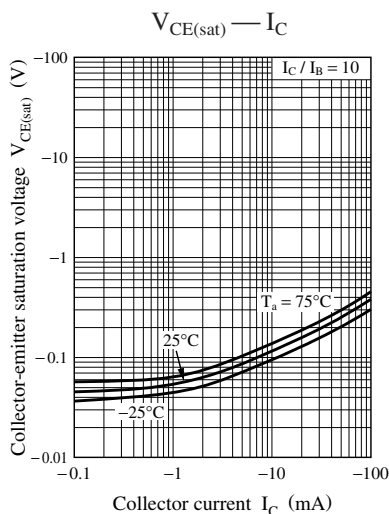
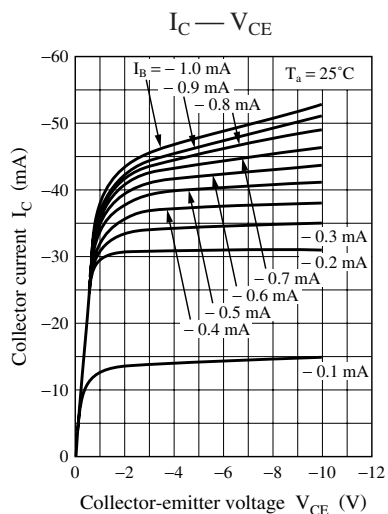


Characteristics charts of UNR4119

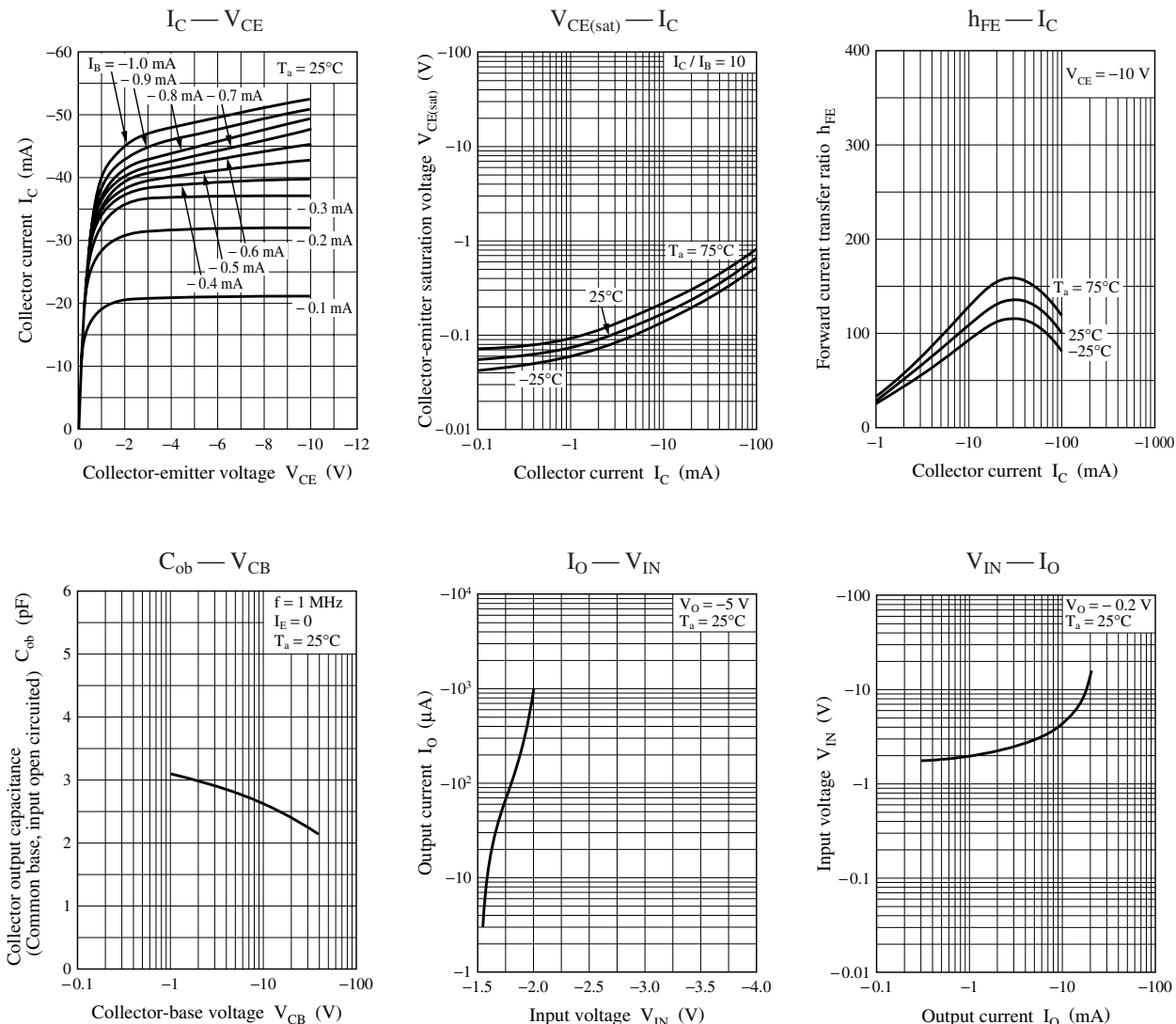




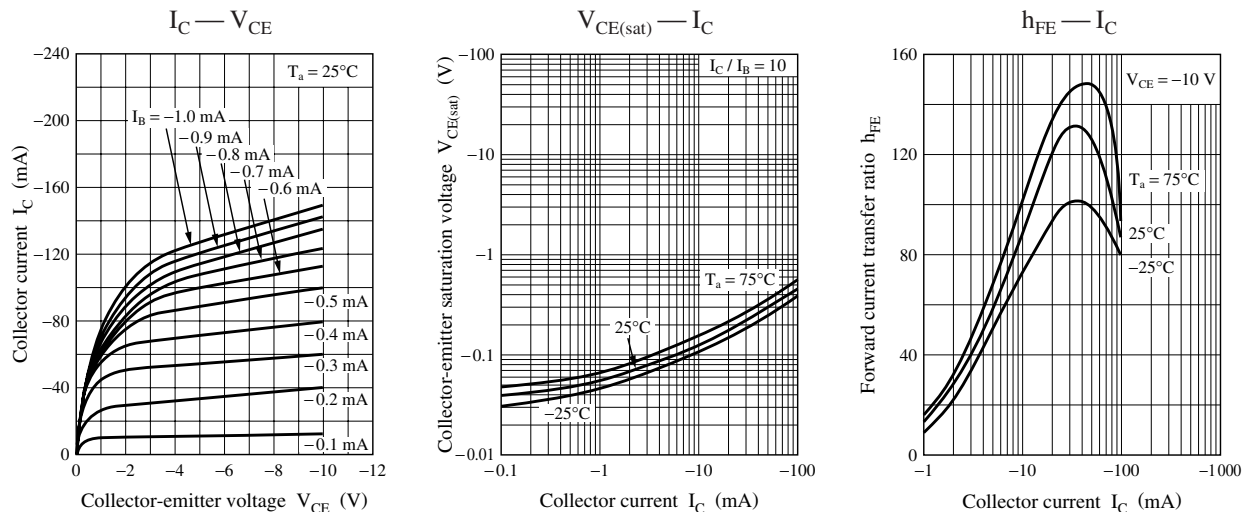
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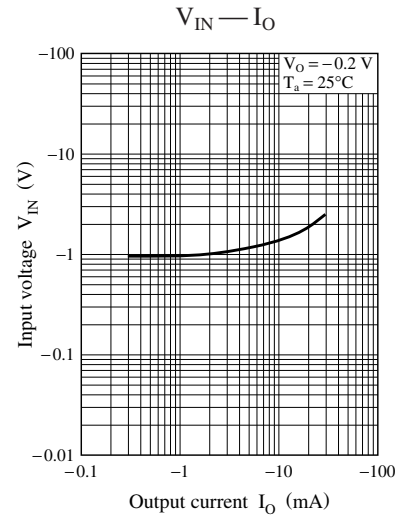
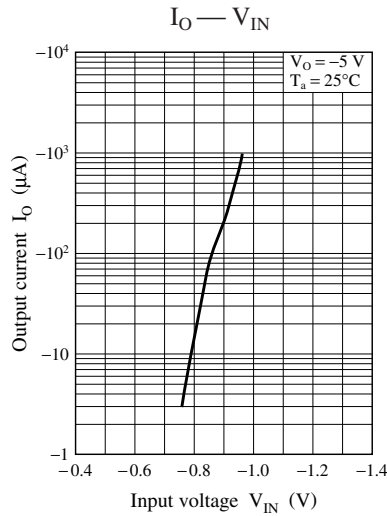
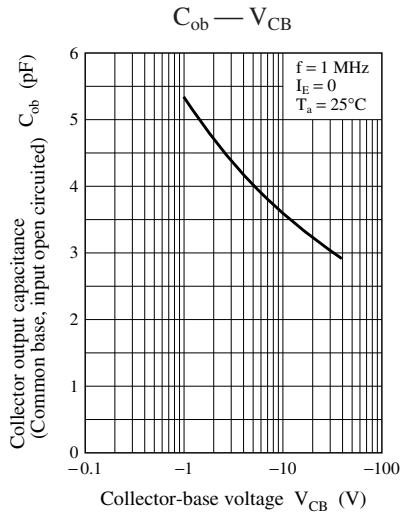


Characteristics charts of UNR411E

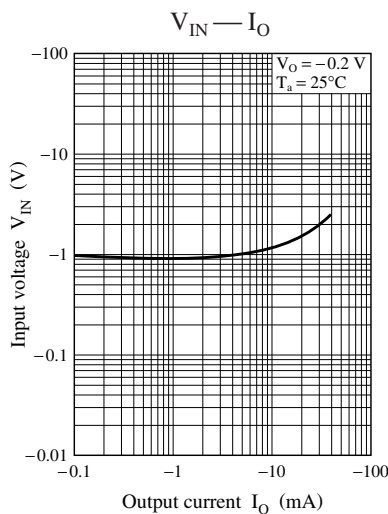
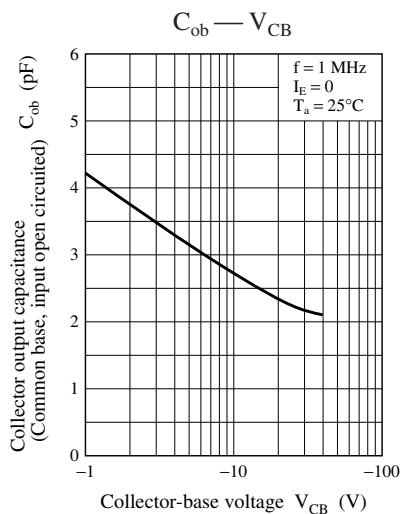
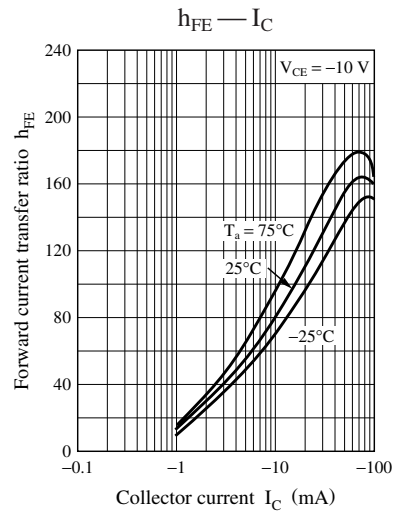
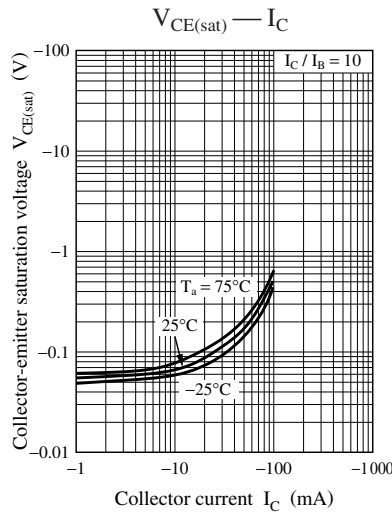
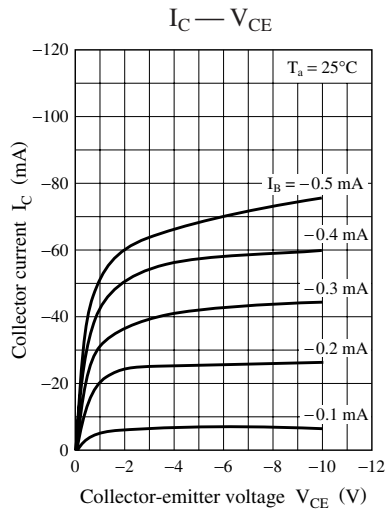


Characteristics charts of UNR411F

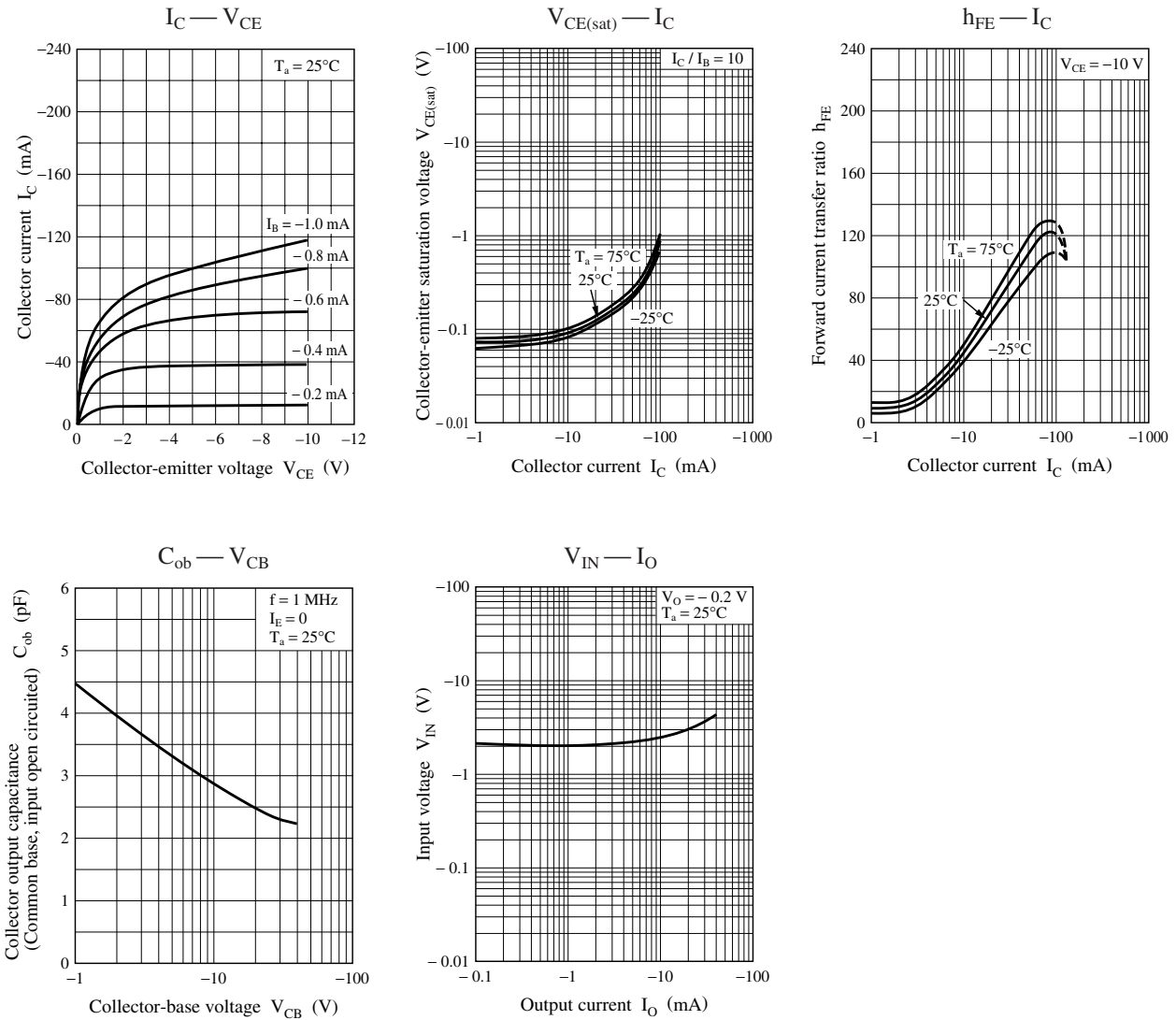




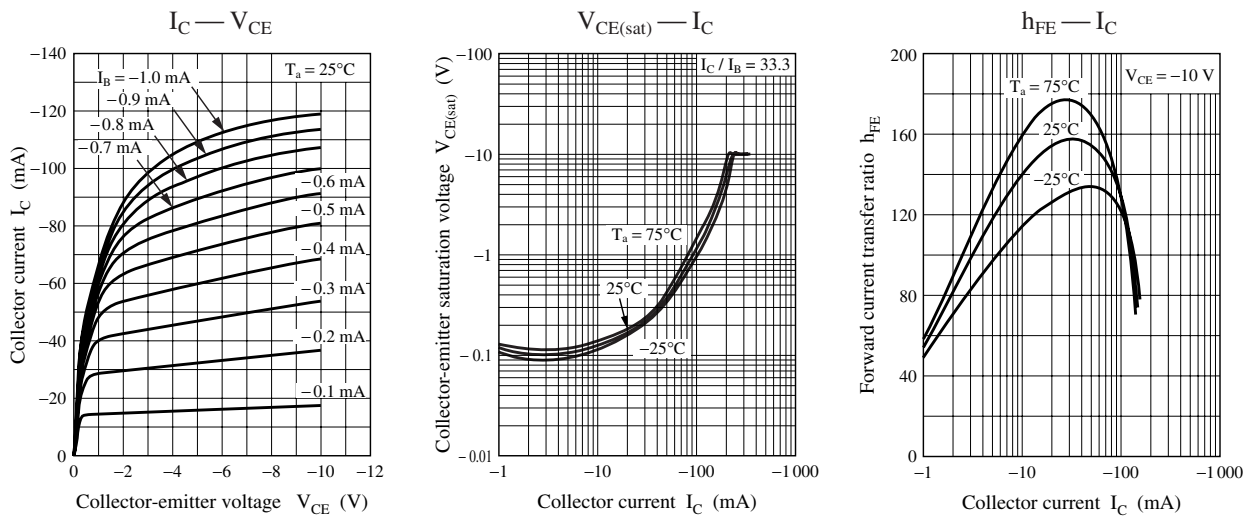
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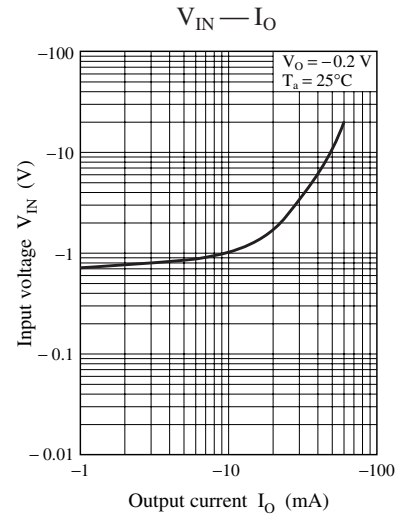
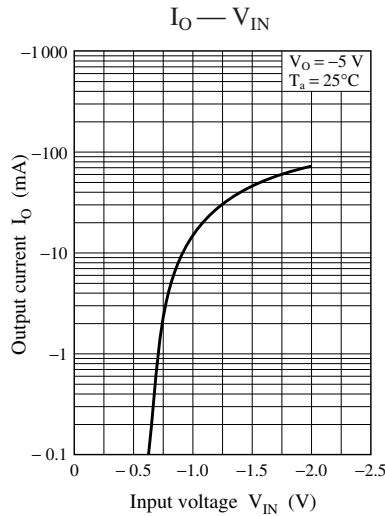
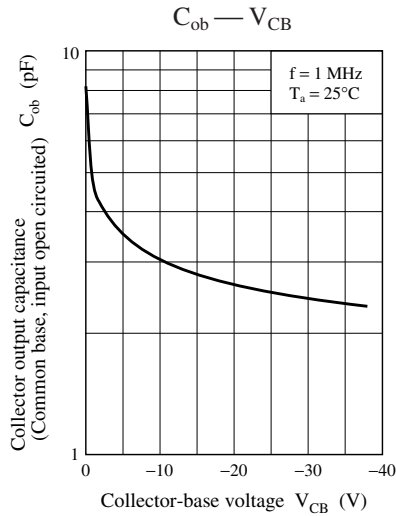


Characteristics charts of UNR411L

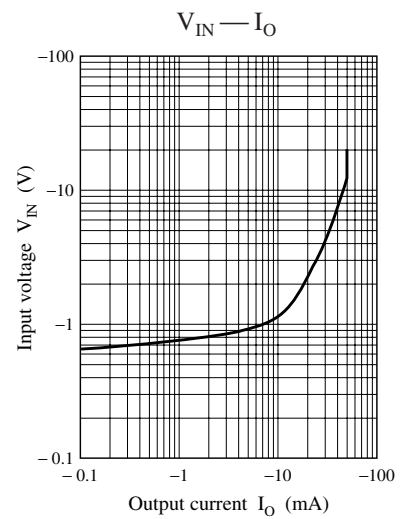
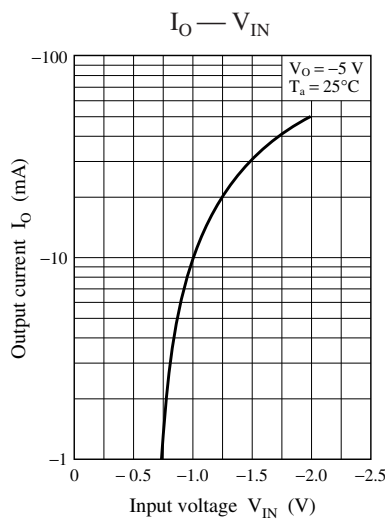
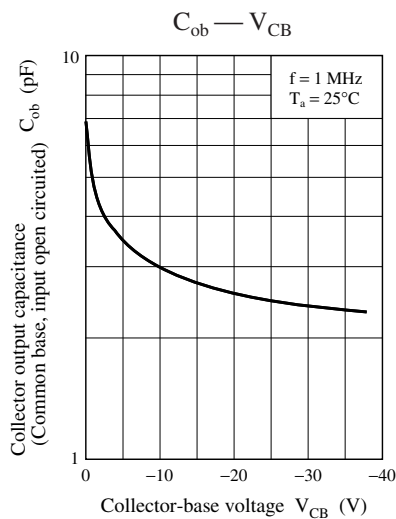
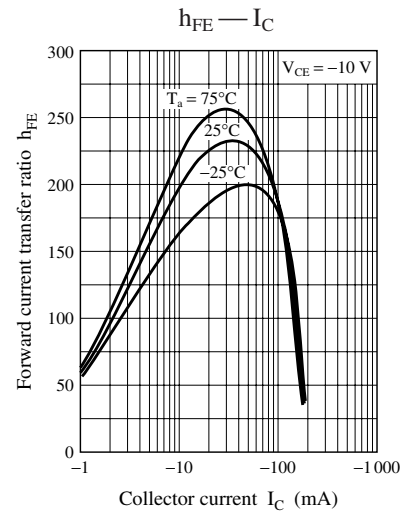
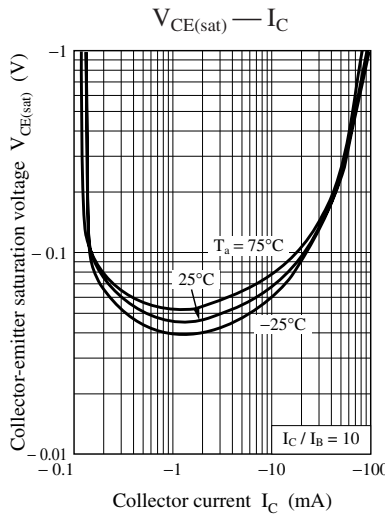
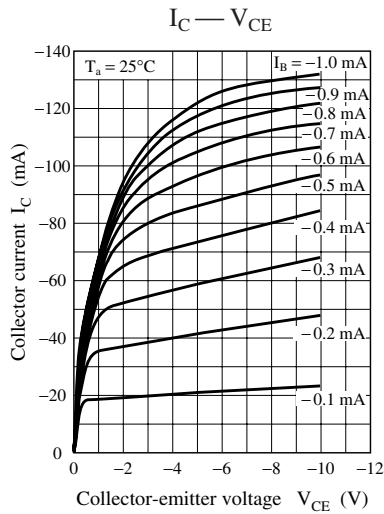


Characteristics charts of UNR411M





Characteristics charts of UNR411N



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